

PSMN1R1-30YLE

N-channel 30 V, 1.3 mOhm, ASFET for hotswap with enhanced SOA in LFPAK56

17 October 2022

Product data sheet

1. General description

N-channel enhancement mode ASFET for hotswap with enhanced SOA in LFPAK56 package optimized for low R_{DSon} and strong safe operating area, optimized for hot-swap, inrush and linear-mode applications.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Optimized for low R_{DSon} / low I²R conduction losses
- LFPAK56 package for applications that demand the highest performance and reliability in a 30 mm² footprint
- Low leakage <1 µA at 25 °C
- Copper-clip for low parasitic inductance and resistance
- High reliability LFPAK package, qualified to 175 °C

3. Applications

- Hot swap in 12 V 20 V applications
- e-Fuse
- DC switch
- · Load switch
- Battery protection

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	30	V		
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	265	Α		
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	192	W		
Tj	junction temperature			-55	-	175	°C		
Static characte	eristics								
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	1.01	1.26	mΩ		
		$V_{GS} = 7 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 10$		-	1.28	1.8	mΩ		
Dynamic chara	Dynamic characteristics								
Q_{GD}	gate-drain charge	$I_D = 25 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V};$		2	9	18	nC		
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>		13	28	46	nC		



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode							
S		$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 15 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 16$		-	1	-	

^{[1] 265} A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	
2	S	source		D
3	S	source	a	
4	G	gate		G_() (
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	mbb076 S

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN1R1-30YLE	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R1-30YLE	1E1L30Y

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	30	V
V_{DGR}	drain-gate voltage	25 °C ≤ T _j ≤ 175 °C; R _{GS} = 20 kΩ		-	30	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	192	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	265	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	202	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	1142	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C

Symbol	Parameter	Conditions		Min	Max	Unit
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drai	n diode			·	•	
Is	source current	T _{mb} = 25 °C		-	192	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$		-	1142	Α
Avalanche r	ruggedness				•	
E _{DS(AL)S}		I_D = 25 A; V_{sup} ≤ 30 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 2 ms	[2]	-	1	J
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 30 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega$	[2]	-	115	А

^{[1] 265} A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

^[2] Protected by 100% test.

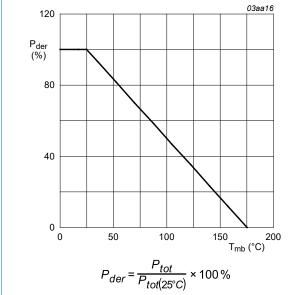
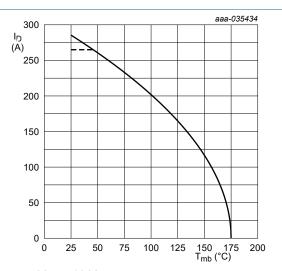
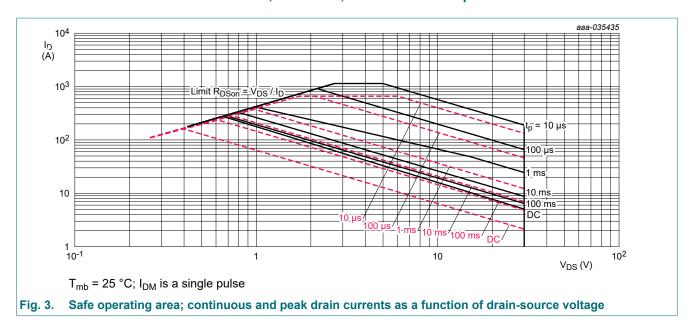


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$ (1) 265 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

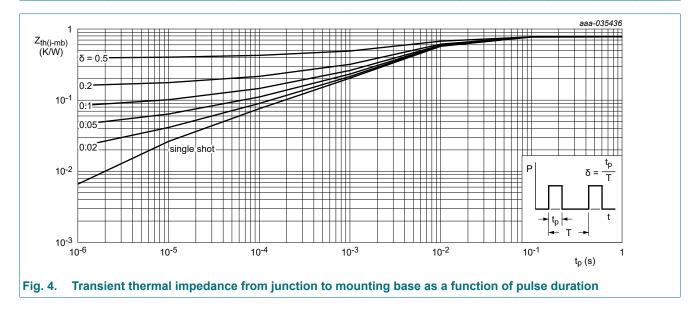
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	0.38	0.78	K/W
R _{th(j-a)}	thermal resistance from	Fig. <u>5</u>	-	42	-	K/W
	junction to ambient	Fig. 6	-	85	-	K/W



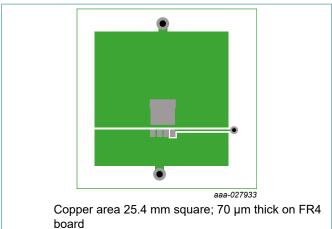
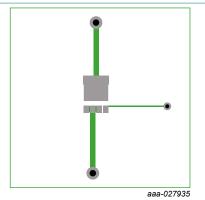


Fig. 5. PCB layout for thermal resistance from junction to ambient



70 µm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static charac	teristics						
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V	
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	27	-	-	V	
V _{GS(th)}	gate-source threshold voltage	$I_D = 2 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.87	2.2	V	
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-3.7	-	mV/K	
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA	
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	6.4	-	μA	
I _{GSS} gate	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA	
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA	
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	1.01	1.26	mΩ	
		V_{GS} = 10 V; I_D = 25 A; T_j = 150 °C; Fig. 11	-	-	2.3	mΩ	
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.28	1.8	mΩ	
		V _{GS} = 7 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	3.3	mΩ	
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	1.2	3	7.5	Ω	
Dynamic cha	racteristics						
Q _{G(tot)}	Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>	13	28	46	nC
			I _D = 25 A; V _{DS} = 15 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>	28	62	102	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; T _j = 25 °C	-	32	-	nC	

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		3.5	13	25	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 12; Fig. 13</u>		1.6	6	12	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			1.9	7	13	nC
Q_{GD}	gate-drain charge	1		2	9	18	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 15 V; T _j = 25 °C; Fig. 12; Fig. 13		-	3.5	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		2527	4211	6317	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		1019	1699	2549	pF
C _{rss}	reverse transfer capacitance			80	296	710	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V;		-	35	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$		-	87	-	ns
t _{d(off)}	turn-off delay time			-	24	-	ns
t _f	fall time	1		-	32	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	38	-	nC
Source-dra	in diode			'			,
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 15$		-	0.79	1	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	31	-	ns
Q _r	recovered charge	V _{DS} = 15 V; T _j = 25 °C; <u>Fig. 16</u>	[1]	-	23	-	nC
t _a	reverse recovery rise time			-	15.7	-	ns
t _b	reverse recovery fall time			-	15.6	-	ns
S	softness factor			-	1	-	

[1] includes capacitive recovery

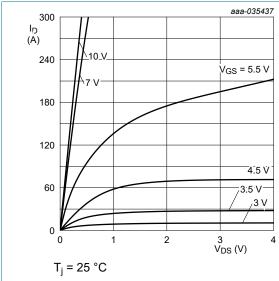


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

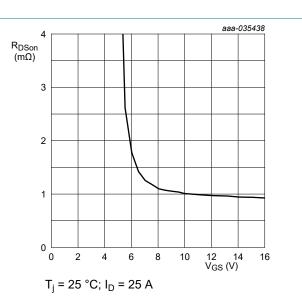


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

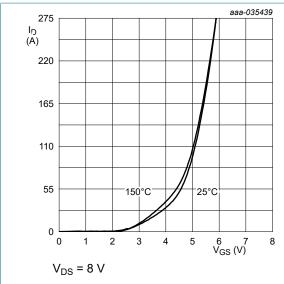


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

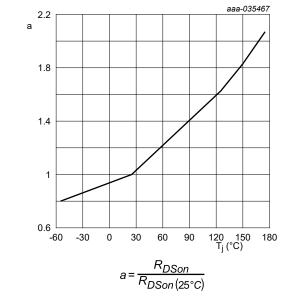


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

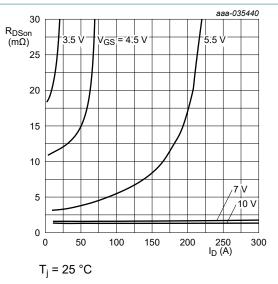


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

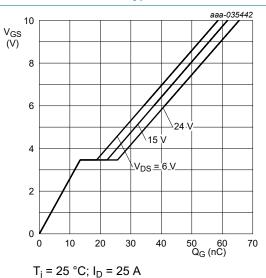


Fig. 12. Gate-source voltage as a function of gate charge; typical values

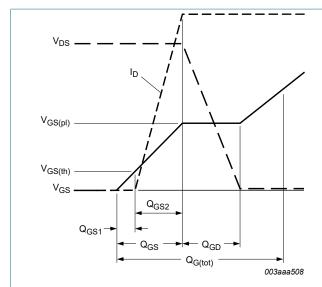
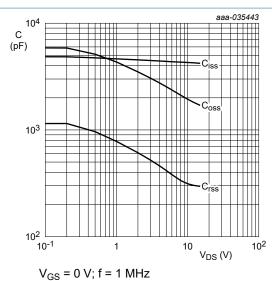


Fig. 13. Gate charge waveform definitions



V_{GS} - U V, I - I IVIHZ

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

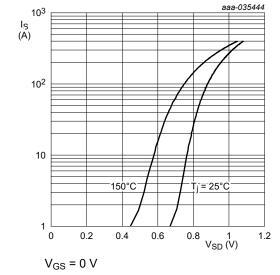


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

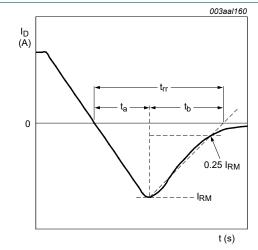


Fig. 16. Reverse recovery timing definition

11. Package outline

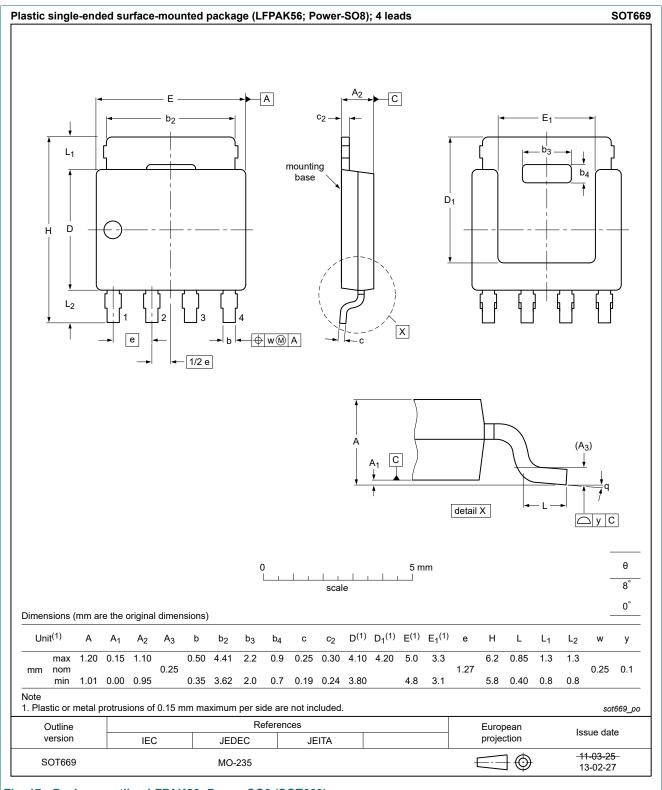
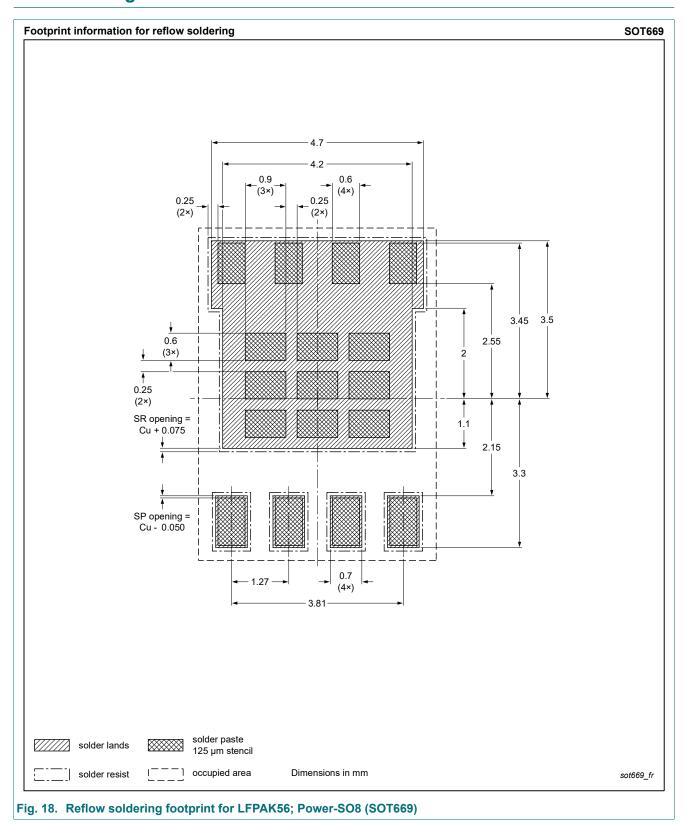


Fig. 17. Package outline LFPAK56; Power-SO8 (SOT669)

12. Soldering



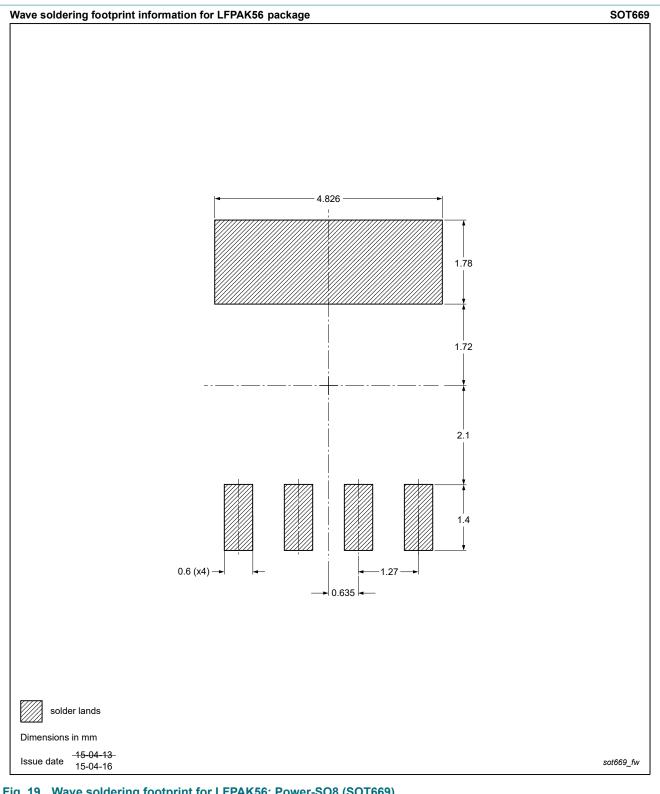


Fig. 19. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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